

PJQ2888

20V P-Channel Enhancement Mode MOSFET with TVS Diode

Voltage **-20 V** **Current** **-1.5A**

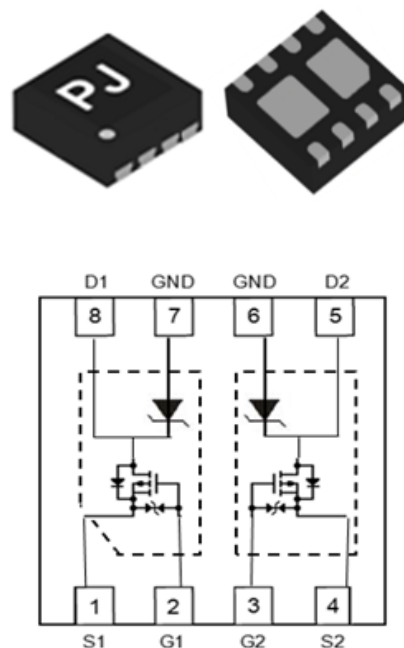
Features

- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_D@-1.5A < 325m\Omega$
- $R_{DS(ON)}$, $V_{GS}@-2.5V$, $I_D@-1.2A < 420m\Omega$
- $R_{DS(ON)}$, $V_{GS}@-2.5V$, $I_D@-0.5A < 600m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std.
(Halogen Free)

Mechanical Data

- Case : DFN2020-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.00032 ounces, 0.0093 grams
- Marking : 888

DFN2020-8L



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-20	V
Gate-Source Voltage		V _{GS}	±8	V
Continuous Drain Current		I _D	-1.5	A
Pulsed Drain Current (Note 4)		I _{DM}	-6.0	A
Power Dissipation	T _a =25°C	P _D	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		T _J , T _{STG}	-55~150	°C
Typical Thermal resistance		R _{θJA}	100	°C/W
- Junction to Ambient (Note 3)				



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Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-20	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-0.4	-0.64	-1.0	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-4.5V, I _D =-1.5A	-	240	325	mΩ
		V _{GS} =-2.5V, I _D =-1.2A	-	295	420	
		V _{GS} =-1.8V, I _D =-0.5A	-	405	600	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0V	-	-0.02	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±8V, V _{DS} =0V	-	±3.5	±10	uA
Dynamic						
Total Gate Charge	Q _g	V _{DS} =-10V, I _D =-1.5A, V _{GS} =-4.5V ^(Note 1,2)	-	2.2	-	nC
Gate-Source Charge	Q _{gs}		-	0.4	-	
Gate-Drain Charge	Q _{gd}		-	0.5	-	
Input Capacitance	C _{iss}	V _{DS} =-10V, V _{GS} =0V, f=1.0MHZ	-	150	-	pF
Output Capacitance	C _{oss}		-	27	-	
Reverse Transfer Capacitance	C _{rss}		-	9	-	
Switching						
Turn-On Delay Time	td _(on)	V _{DD} =-10V, I _D =-1.5A, V _{GS} =-4.5V, R _G =6Ω ^(Note 1,2)	-	11	-	ns
Turn-On Rise Time	tr		-	38	-	
Turn-Off Delay Time	td _(off)		-	130	-	
Turn-Off Fall Time	tf		-	75	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S	---	-	-	-1.0	A
Diode Forward Voltage	V _{SD}	I _S =-1A, V _{GS} =0V	-	-0.93	-1.2	V

NOTES :

1. Pulse width≤300us, Duty cycle≤2%
2. Essentially independent of operating temperature typical characteristics.
3. R_{ΘJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.



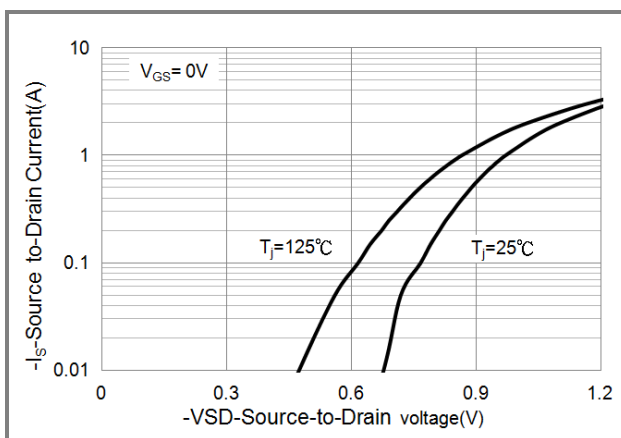
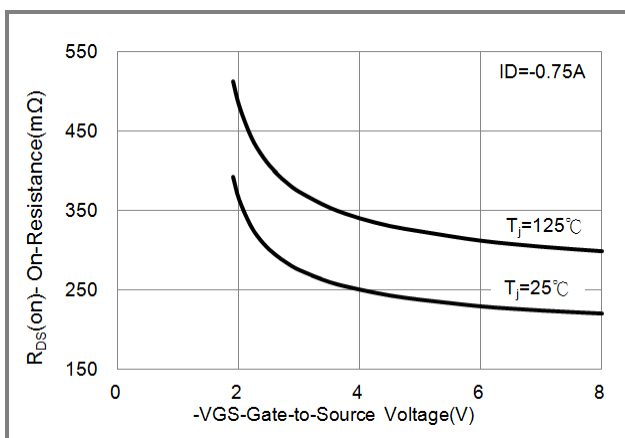
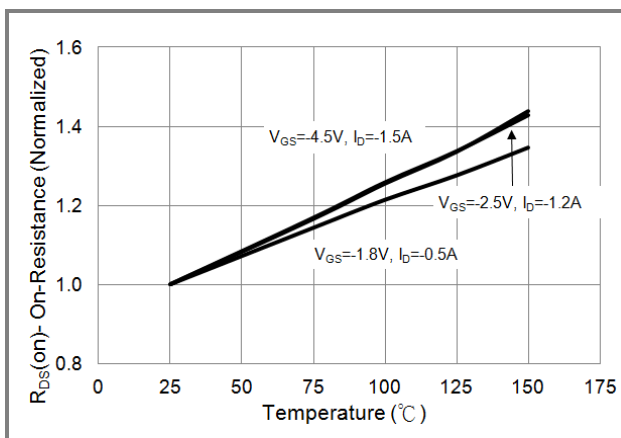
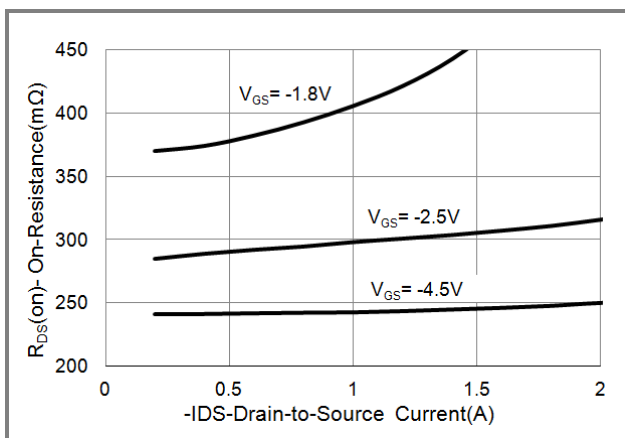
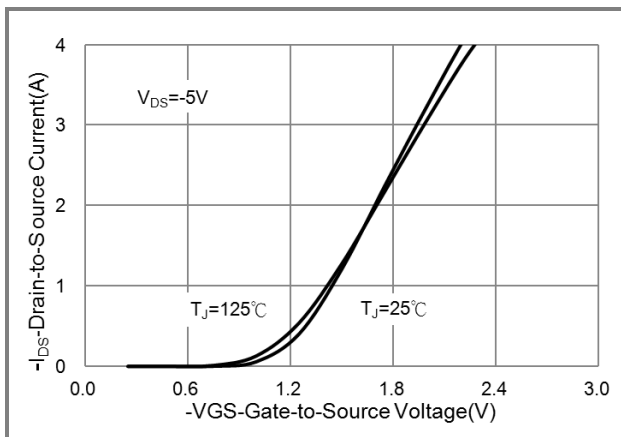
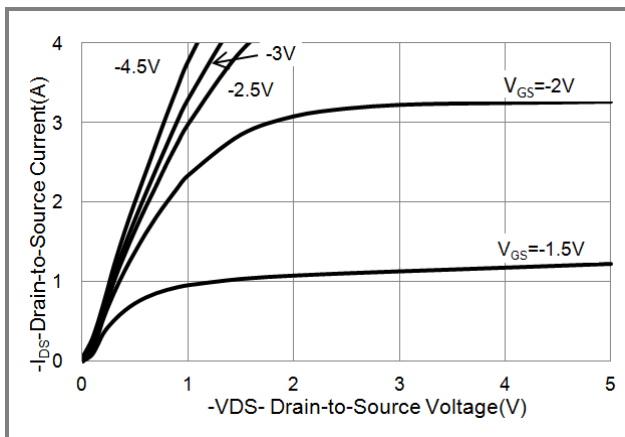
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Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
TVS Diode						
Working Peak Reverse Voltage	V_{RWM}	---	-	-	15	V
Maximum Reverse Leakage Current	I_R	$V_{RWM}=15\text{V}$	-	-	1	μA
Breakdown Voltage	V_{BR}	$I_T=1\text{mA}$	17	-	-	V
Max. Capacitance	C_J	$f=1\text{MHz}$, $V_R=0\text{V}$	-	-	15	pF
Clamping Voltage	V_C	Max Per 8x20us	-	-	30	V
Maximum Reverse Peak Pulse Current	I_{PP}	---	-	-	2	A
Test Current	I_T	---	-	-	1.0	mA

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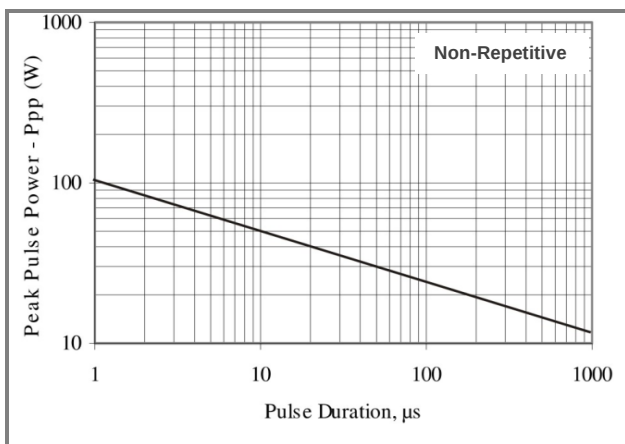
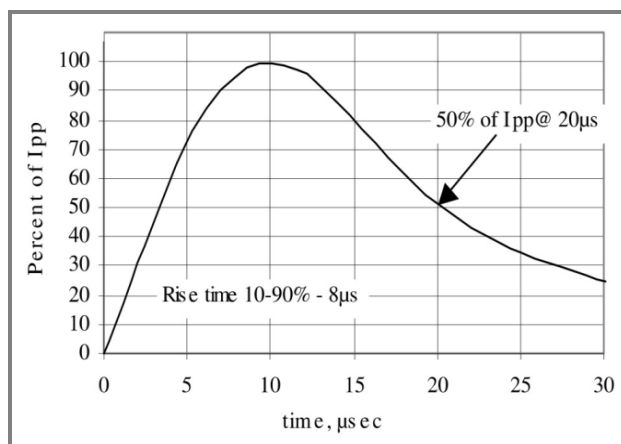
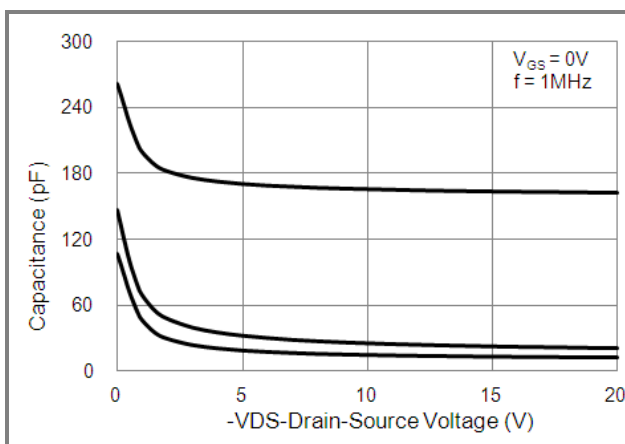
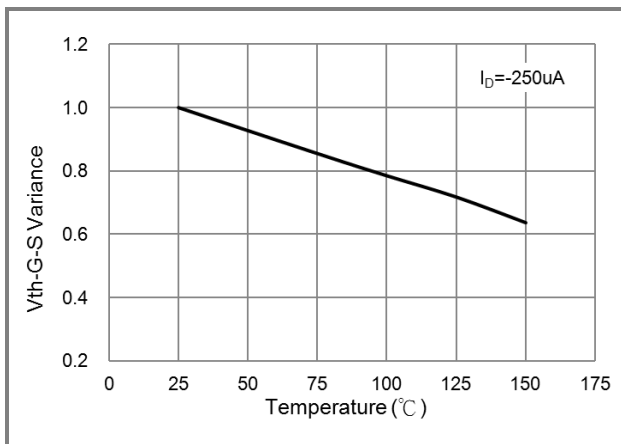
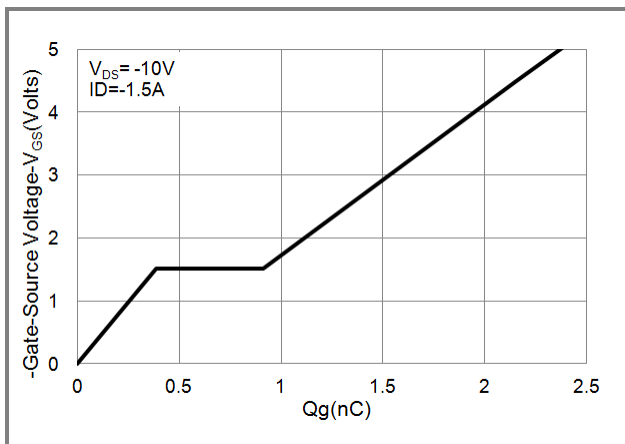
TYPICAL CHARACTERISTIC CURVES





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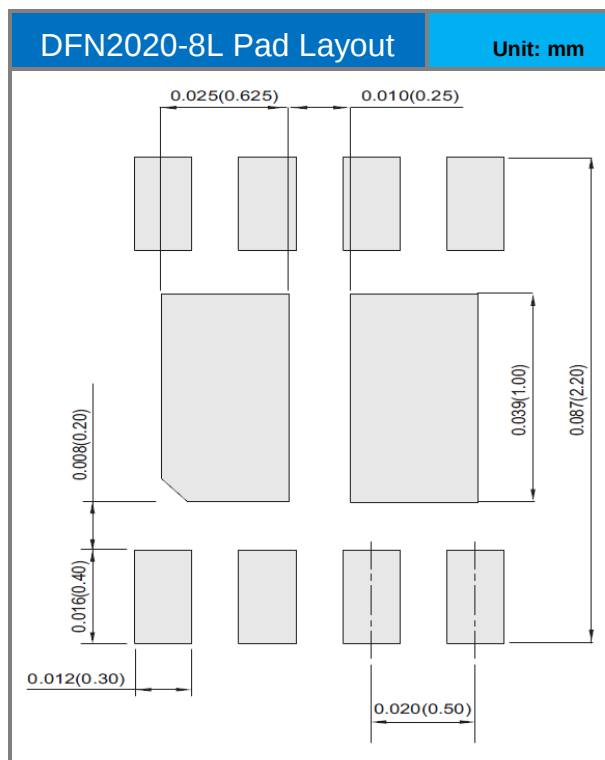
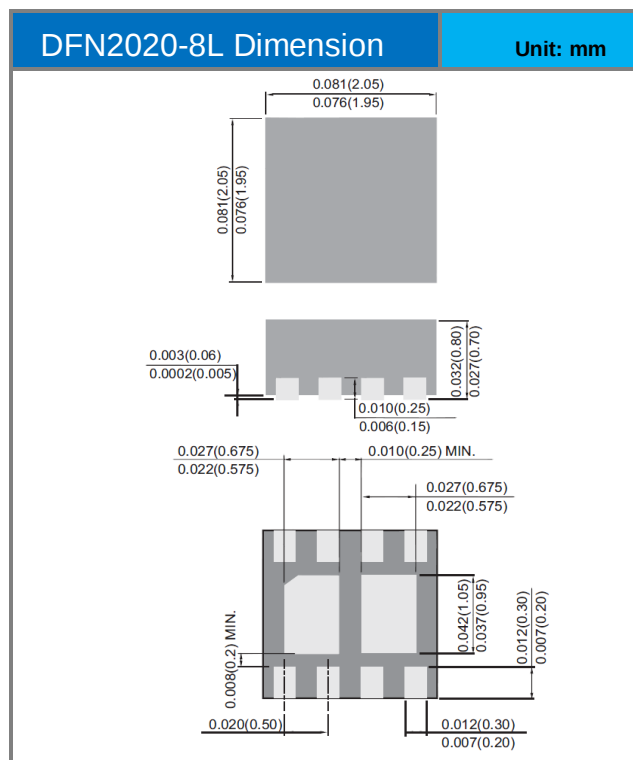


PJQ2888

PART NO PACKING CODE VERSION

PART NO PACKING CODE	Package Type	Packing type	Marking	Version
PJQ2888_R1_00001	DFN2020-8L	3K pcs / 7" reel	888	Halogen free

MOUNTING PAD LAYOUT





PJQ2888

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